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10/21/2008

**REPLY UNDER 37 CFR 1.116
EXPEDITED PROCEDURE
TECHNOLOGY CENTER 1700**

Attorney Docket No. 015675.P556

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Patent Application of:

Hacene Lahreche, et al.

Application No. 10/516,358

Filed: November 24, 2004

For: **METHOD FOR EPITAXIAL
GROWTH OF A GALLIUM NITRIDE FILM
SEPARATED FROM ITS SUBSTRATE**

Examiner: Matthew J. Song

Art Unit: 1792

Confirmation No. 2705

AMENDMENT AND RESPONSE TO FINAL OFFICE ACTION

Mail Stop AF
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

In response to the Final Office Action dated August 8, 2008, Applicants submit the following amendments and remarks: